

## BD234/236/238

# Medium Power Linear and Switching Applications

• Complement to BD 233/235/237 respectively



# **PNP Epitaxial Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage		
020	: BD234	- 45	V
	: BD236	- 60	V
	: BD238	- 100	V
V <sub>CEO</sub>	Collector-Emitter Voltage		
	: BD234	- 45	V
	: BD236	- 60	V
	: BD238	- 80	V
V <sub>CER</sub>	Collector-Emitter Voltage		
	: BD234	- 45	V
	: BD236	- 60	V
	: BD238	- 100	V
V <sub>EBO</sub>	Emitter-Base Voltage	- 5	V
I <sub>C</sub>	Collector Current (DC)	- 2	Α
I <sub>CP</sub>	*Collector Current (Pulse)	- 6	Α
$P_{C}$	Collector Dissipation (T <sub>C</sub> =25°C)	25	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 65 ~ 150	°C

### **Electrical Characteristics** $T_C=25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V <sub>CEO</sub> (sus)	* Collector-Emitter Sustaining Voltage					
	: BD234	$I_C = -100 \text{mA}, I_B = 0$	- 45			V
	: BD236		- 60			V
	: BD238		- 80			V
I <sub>CBO</sub>	Collector Cut-off Current					
	: BD234	$V_{CB} = -45V, I_{E} = 0$			- 100	μΑ
	: BD236	$V_{CB} = -60V, I_{E} = 0$			- 100	μΑ
	: BD238	$V_{CB} = -100V, I_{E} = 0$			- 100	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = -5V, I_{C} = 0$			- 1	mA
h <sub>FE</sub>	* DC Current Gain	$V_{CE} = -2V, I_{C} = -150mA$	40			
		$V_{CE} = -2V, I_{C} = -1A$	25			
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	$I_C = -1A$ , $I_B = -0.1A$			- 0.6	V
V <sub>BE</sub> (on)	* Base-Emitter ON Voltage	V <sub>CE</sub> = - 2V, I <sub>C</sub> = - 1A			- 1.3	V
f⊤	Current Gain Bandwidth Product	$V_{CE} = -10V, I_{C} = -250mA$	3			MHz

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# **Typical Characteristics**

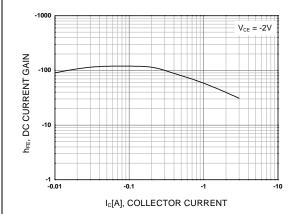


Figure 1. DC current Gain

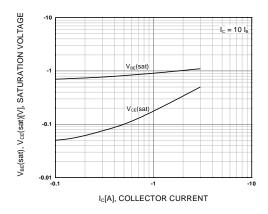


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

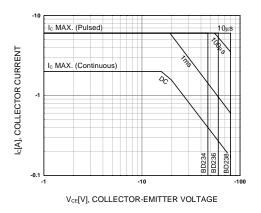


Figure 3. Safe Operating Area

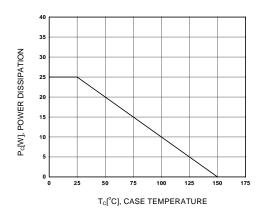
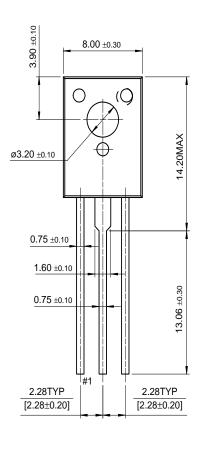
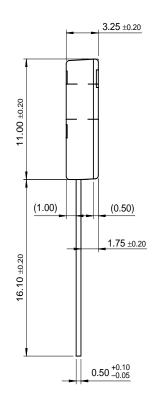


Figure 4. Power Derating

TO-126







Dimensions in Millimeters

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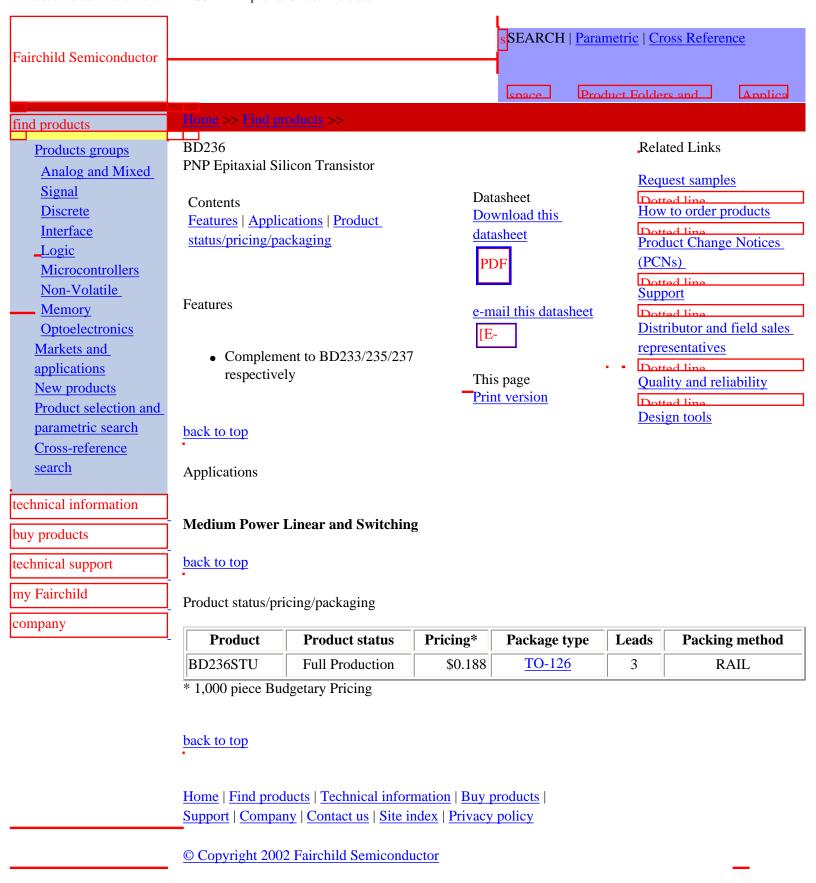
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